

100 mA low V_F MEGA Schottky barrier rectifier Rev. 1 — 24 January 2011

Product data sheet

Product profile 1.

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD882 leadless ultra small Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Average forward current: I_{F(AV)} ≤ 100 mA
- Reverse voltage: V_R ≤ 30 V
- Low forward voltage: V_F ≤ 350 mV
- Low reverse current: $I_R \le 10 \ \mu A$
- AEC-Q101 qualified
- Leadless ultra small SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{F(AV)}	average forward current	square wave; δ = 0.5; f = 20 kHz				
		$T_{amb} \le 135 \ ^{\circ}C$	<u>[1]</u> -	-	100	mA
		$T_{sp} \le 145 \ ^{\circ}C$	-	-	100	mA
I _R	reverse current	V _R = 10 V	-	2	10	μΑ
V _R	reverse voltage		-	-	30	V
V _F	forward voltage	I _F = 10 mA	[2] _	280	350	mV

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 1 cm².

 $\label{eq:pulse test: t_p large 300 } \text{ } \mu\text{s}; \, \delta \leq 0.02.$



100 mA low V_F MEGA Schottky barrier rectifier

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	cathode	<u>[1]</u>	
2	anode	1 2	1 <u>-</u> 2 sym001
		Transparent top view	

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Orde	ering informati	ion	
Type number	Package		
	Name	Description	Version
RB521CS30L	-	leadless ultra small plastic package; 2 terminal; body 1.0 \times 0.6 \times 0.5 mm	SOD882

4. Marking

Table 4. Marking codes	
Type number	Marking code
RB521CS30L	AR

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	reverse voltage		-	30	V
I _{F(AV)}	average forward current	square wave; $\delta = 0.5$; f = 20 kHz			
		$T_{amb} \le 135 \ ^{\circ}C$	<u>[1]</u> -	100	mA
		$T_{sp} \le 145 \ ^{\circ}C$	-	100	mA
I _{FSM}	non-repetitive peak forward current	half sine wave; $t_p \leq 8.3 \mbox{ ms}$	[2] _	3	А

100 mA low V_F MEGA Schottky barrier rectifier

Table 5.	Limiting	values	continued
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In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[4][3]</u>	315	mW
			<u>[4][1]</u>	565	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[2] $T_j = 25 \text{ °C prior to surge.}$

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[4] Reflow soldering is the only recommended soldering method.

6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from in free		in free air	[1][2]			
junction to ambient	junction to ambient	on to ambient	[3]	-	395	K/W
			[4] _	-	220	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		<u>[5]</u> _	-	70	K/W

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

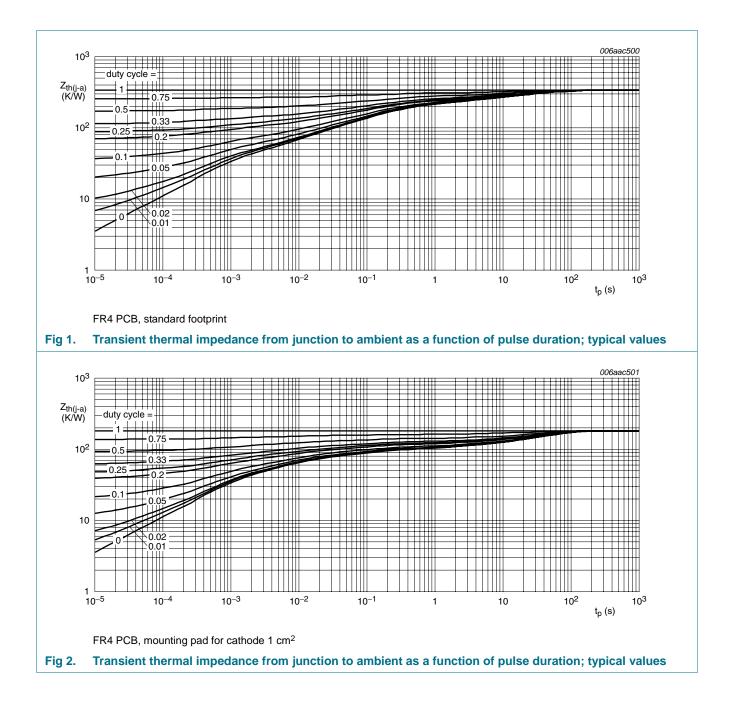
[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[5] Soldering point of cathode tab.

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100 mA low V_F MEGA Schottky barrier rectifier

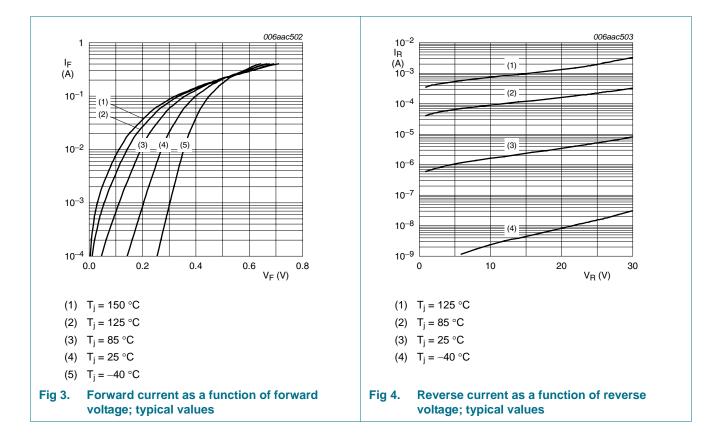


100 mA low V_F MEGA Schottky barrier rectifier

7. Characteristics

Table 7. $T_{amb} = 25^{\circ}$	Characteristics C unless otherwise spec	cified.				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage		<u>[1]</u>			
		I _F = 0.1 mA	-	145	-	mV
		I _F = 1 mA	-	210	-	mV
		I _F = 10 mA	-	280	350	mV
		I _F = 100 mA	-	405	-	mV
I _R	reverse current	V _R = 10 V	-	2	10	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz	-	8	-	pF

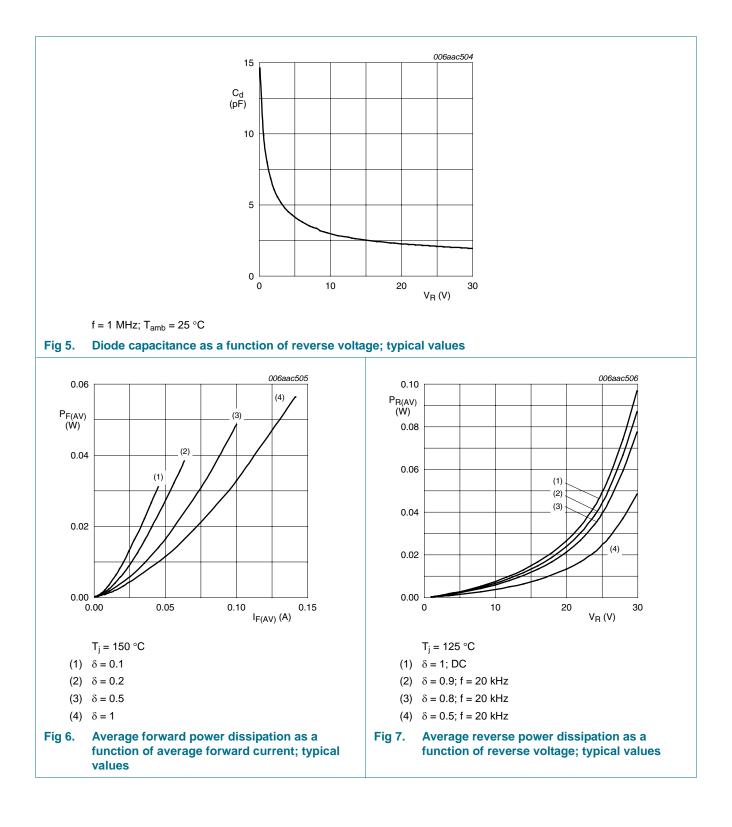
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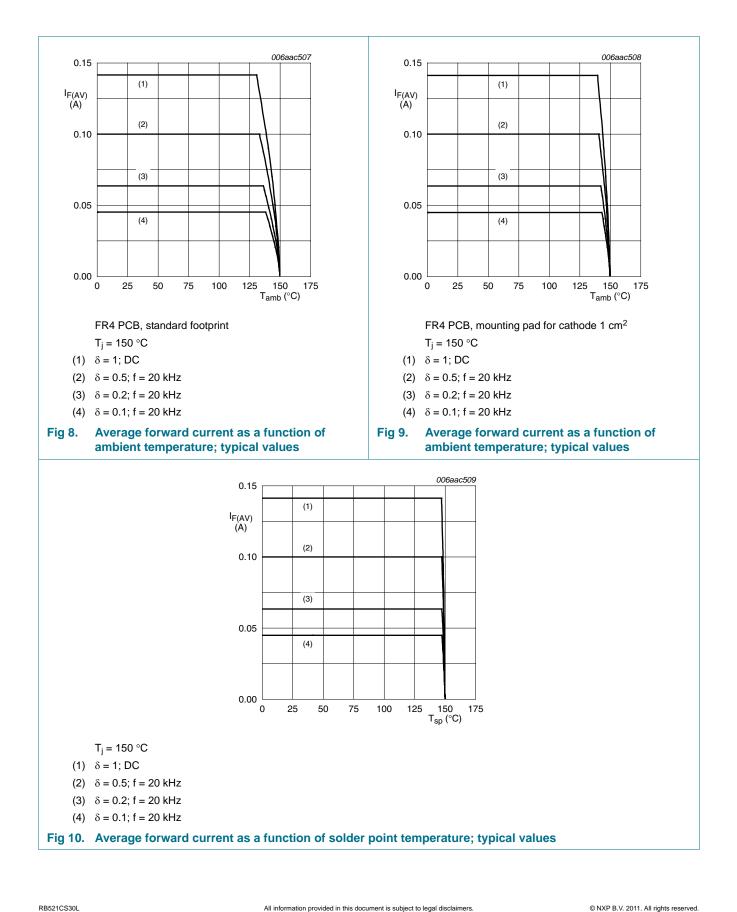


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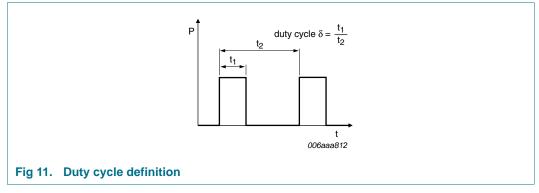
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100 mA low V_F MEGA Schottky barrier rectifier



100 mA low V_F MEGA Schottky barrier rectifier

8. Test information

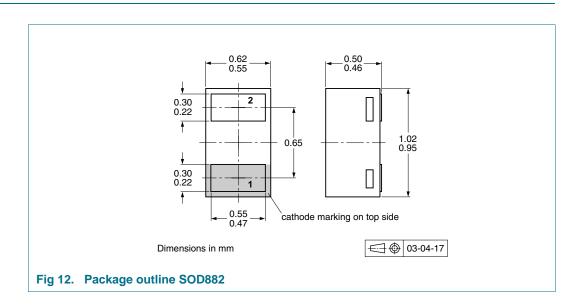


The current ratings for the typical waveforms as shown in Figure 8, 9 and 10 are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current,

 $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.



9. Package outline

RB521CS30L

100 mA low V_F MEGA Schottky barrier rectifier

10. Packing information

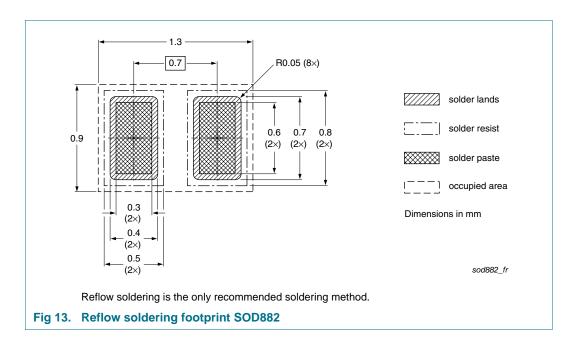
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity 10000
RB521CS30L	SOD882	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see Section 14.

11. Soldering



RB521CS30L Product data sheet

100 mA low V_F MEGA Schottky barrier rectifier

12. Revision history

Table 9. Revision hist	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
RB521CS30L v.1	20110124	Product data sheet	-	-

100 mA low V_F MEGA Schottky barrier rectifier

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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For sales office addresses, please send an email to: salesaddresses@nxp.com

RB521CS30L

100 mA low V_F MEGA Schottky barrier rectifier

15. Contents

1	Product profile 1
1.1	General description 1
1.2	Features and benefits 1
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
5	Limiting values 2
6	Thermal characteristics 3
7	Characteristics 5
8	Test information 8
8.1	Quality information 8
9	Package outline 8
10	Packing information 9
11	Soldering 9
12	Revision history 10
13	Legal information 11
13.1	Data sheet status 11
13.2	Definitions 11
13.3	Disclaimers
13.4	Trademarks 12
14	Contact information 12
15	Contents 13

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Date of release: 24 January 2011 Document identifier: RB521CS30L